# ■ MN101C70C, MN101C70G

Туре	MN101C70C	MN101C70G (under planning)		
ROM (×8-bit)	48 K	128 K		
RAM (×8-bit)	2 K	10 K		
Package	LQFP080-P-1414A *Lead-free, TQFP080-P-1212D *Lead-free (under planning)			
Minimum Instruction Execution Time	0.1 μs (at 3.0 V to 3.6 V, 10 MHz) 0.235 μs (at 1.8 V to 3.6 V, 4.25 MHz) 62.5 μs (at 1.8 V to 3.6 V, 32 kHz)			
Interrupts	• RESET • Watchdog • External 0 • External 1 • External 2 • External 4 (key interrupt dedicated) • Timer 0 • Timer 1 • Timer 2 • Timer 3 • Timer 6 • Time base • Timer 7 (2 systems) • Timer 8 (2 systems) • Serial 0 (2 systems) • Serial 2 • A/D conversion finish • Automatic transfer finish			
Timer Counter	Timer counter 0: 8-bit × 1  (square-wave/8-bit PWM output, event count, generation of remote control carrier, simple pulse width measurement, added pluse (2-bit) system PWM output, real time output control) (square-wave/PWM output to large current terminal P50 possible)  Clock source			
	· · · · · · · · · · · · · · · · · · ·	n clock frequency; 1/1, 1/4, 1/16, 1/64, 1/128 of OSC frequency; 1/1 of XI oscillation clock frequency; external		
	Timer counter 0, 1 can be cascade-connected.			
	Timer counter 2: 8-bit × 1  (square-wave output, added pluse (2-bit) system F time output control, event count, synchronous ou PWM output to large current terminal P52 possib Clock source	n clock frequency; 1/1, 1/4, 1/16, 1/32, 1/64 of OSC oscillation 1/1 of XI oscillation clock frequency; external clock input		
	Timer counter 3: 8-bit × 1  (square-wave output, event count, generation of re  Clock source	emote control carrier, serial transfer clock) a clock frequency; 1/1, 1/4, 1/16, 1/64, 1/128 of OSC frequency; 1/1 of XI oscillation clock frequency; external		
	Timer counter 2, 3 can be cascade-connected.			
	Timer counter 6: 8-bit freerun timer  Clock source 1/1 of system clo	ck frequency; 1/1, 1/128, 1/8192 of OSC oscillation clock /128, 1/8192 of XI oscillation clock frequency compare register 6		
	Timer counter 7 : 16-bit × 1	duty continuous variable), event count, synchronous output		

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oscillation clock frequency; 1/1, 1/2, 1/4, 1/16 of external clock input frequency

event, pulse width measurement, input capture, real time output control, high performance IGBT output (Cycle/

Interrupt source ..... coincidence with compare register 7 (2 lines), input capture register

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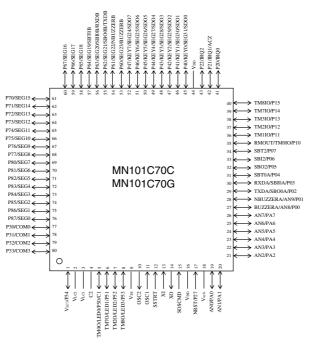
Timer Counter	Timer counter 8: 16 bit × 1	
(Continue)	(square-wave/16-bit PWM output [duty continuous variable], event count, pulse width measurement, input capture) (square-wave/PWM output to large current terminal P53 possible)  Clock source	
	Time base timer (one-minute count setting)  Clock source	
	Watchdog timer Interrupt source	
Serial Interface	Serial 0: synchronous type/UART (full-duplex) × 1  Clock source	
	Serial 2 : synchronous type/single-master I <sup>2</sup> C × 1 Clock source	
I/O Pins I/O	66 • Common use • Specified pull-up resistor available • Input/output selectable (bit unit)	
A/D Inputs	10-bit × 16-ch. (with S/H)	
LCD	32 segments × 4 commons (static, 1/2, 1/3, or 1/4 duty)  LCD power supply separated from VDD (usable if VDD ≤ VLCD ≤ 3.6 V)  LCD power step-up circuit contained (3/2, 2 and 3 times)  LCD power shunt resistance contained LCD reference voltage is contained.	
Special Ports	Buzzer output, remote control carrier signal output, high-current drive port	

#### **Electrical Characteristics**

#### Supply current

Parameter	Symbol	condition -		Limit		
raiailietei	Syllibol			typ	max	Unit
	IDD1	fosc = 4 MHz, VDD = 3 V		1	2	mA
Operatingsupplycurrent	IDD2	fx = 32  kHz, VDD = 3  V		4	15	μА
Supply current at HALT	IDD3	$fx = 32 \text{ kHz}, VDD = 3 \text{ V}, Ta = 25^{\circ}\text{C}$		2	10	μА
	IDD4	$fx = 32 \text{ kHz}, VDD = 3 \text{ V}, Ta = -40^{\circ}\text{C to} +85^{\circ}\text{C}$			40	μА
	IDD5	VDD = 3 V, Ta = 25°C			2	μА
Supply current at STOP	IDD6	$VDD = 3 \text{ V}, \text{ Ta} = -40^{\circ}\text{C to } +85^{\circ}\text{C}$			30	μА

#### Pin Assignment



LQFP080-P-1414A \*Lead-free TQFP080-P-1212D \*Lead-free

#### **Support Tool**

In-circuit Emulator	PX-ICE101C / D + PX-PRB101C70-LQFP080-P-1414A-M (under development) PX-ICE101C / D + PX-PRB101C70-TQFP080-P-1212-M (under planning)	
Flash Memory Built-in Type	Туре	MN101CF70G (under development)
	ROM (× 8-bit)	128 K
	RAM (× 8-bit)	10 K
	Minimum instruction execution time	0.1 µs (at 3.0 V to 3.6 V, 10 MHz)
		$0.235~\mu s$ (at $1.8~V$ to $3.6~V,4.25~MHz)$
		62.5 µs (at 1.8 V to 3.6 V, 32 kHz)
	Package	LQFP080-P-1414A *Lead-free, TQFP080-P-1212D *Lead-free (under planning)

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